

Smart "Compact" range without display CB20 Smart Part number 88974033



- Efficient and economical version, without display or keys setting
 Allow the use of the entire library of specific functions blocs of the software workshop
- Extended temperature range (-30 °C →+70 °C)
- Analogue inputs 0-10 VDC, Potentiometer, NTC, LDR (0-20 mA/Pt100 with converters)

Part numbers

Туре	Inputs	Outputs	Supply
88974033 CB20 Smart	12 digital	8 relays 8 A	100 →240 V AC

Specifications

General environment	charactoristics	for CB CD VD	VP VP and VI	nroduct types
General environment	characteristics	TOT U.D. U.D. AD.	. AD. AK ANG AI	= product types

General environment characteristics for CB, CD, 7	
Certifications	CE, UL, CSA, GL
Conformity to standards (with the low voltage directive	IEC/EN 61131-2 (Open equipment)
and EMC directive)	IEC/EN 61131-2 (Zone B)
	IEC/EN 61000-6-2,
	IEC/EN 61000-6-3 (*)
	IEC/EN 61000-6-4
	(*) Except configuration (88 970 1.1 or 88 970 1.2) + (88 970 250 or 88 970 270) + 88 970 241 class A (class B in a metal enclosure)
Earthing	Not included
Protection rating	In accordance with IEC/EN 60529:
	IP40 on front panel
	IP20 on terminal block
Overvoltage category	3 in accordance with IEC/EN 60664-1
Pollution	Degree : 2 in accordance with IEC/EN 61131-2
Max operating Altitude	Operation : 2000 m
	Transport: 3048 m
Mechanical resistance	Immunity to vibrations IEC/EN 60068-2-6, test Fc
Weeklanda redictaries	Immunity to shock IEC/EN 60068-2-27, test Ea
Resistance to electrostatic discharge	Immunity to ESD
- Trobiotarios to cicetrostatio discriarge	IEC/EN 61000-4-2, level 3
Resistance to HF interference	Immunity to radiated electrostatic fields
resistance to the interference	Infilinity to address discussion lends
	Immunity to fast transients (burst immunity)
	IEC/EN 61000-4-4, level 3
	Immunity to shock waves
	IEC/EN 61000-4-5
	Radio frequency in common mode
	IEC/EN 61000-4-6, level 3
	Voltage dips and breaks (AC)
	IEC/EN 61000-4-11
	Immunity to damped oscillatory waves
	IEC/EN 61000-4-12
Conducted and radiated emissions	Class B (*) in accordance with EN 55022, EN 55011 (CISPR22, CISPR11) group 1
	(*) Except configuration (88 970 1.1 or 88 970 1.2) +
	(88 970 250 or 88 970 270) + 88 970 241 class A (class B in a metal enclosure)
Operating temperature	-20 →+70 °C
	except CB and XB versions in VDC : -30 →+70 °C (+40 °C in a non-ventilated enclosure)
	in accordance with IEC/EN 60068-2-1 and IEC/EN 60068-22
Storage temperature	-40 →+80 °C in accordance with IEC/EN 60068-2-1 and
	IEC/EN 60068-2-2
Relative humidity	95 % max. (no condensation or dripping water) in accordance with
	IEC/EN 60068-2-30
Mounting	On symmetrical DIN rail, 35 x 7.5 mm and 35 x 15 mm, or on panel (2 x Ø 4 mm)
Screw terminals connection capacity	Flexible wire with ferrule =
	1 conductor : 0.25 to 2.5 mm ² (AWG 24AWG 14)
	2 conductors 0.25 to 0.75 mm ² (AWG 24AWG 18)
	2 conductors 0.25 to 0.75 min (AVVG 24AVVG 16) Semi-rigid wire =
	· ·
	1 conductor : 0.2 to 2.5 mm ² (AWG 25AWG 14)
	Rigid wire =
	1 conductor : 0.2 to 2.5 mm ² (AWG 25AWG 14)
	2 conductors 0.2 to 1.5 mm ² (AWG 25AWG 16)
	Tightening torque =
	0.5 N.m (4.5 lb-in) (tighten using screwdriver diam. 3.5 mm)
	Also valid for spring cage connectors (ref 88 970 313 and 88 970 317 for the RBT range)

General characteristics

-30 →+70 °C (DC) ; -20 →+70 °C (AC)

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Operating factor	100 % (6 A relays)			
Storage temperature	66 % (8 A relays) -40 →+80 °C			
Processing characteristics of CB, CD, XD & XB				
LCD display	CD, XD : Display with 4 lines of 18 characters			
Programming method	Function blocks / SCF (Grafcet) or Ladder			
Program size		8 Kb : 350 typical blocks, 64 macros maximum, 256 blocks maximum per macro		
	or 120 lines in Ladder			
Program memory	Flash EEPROM			
Removable memory	EEPROM			
Data memory	368 bit/200 words			
Back-up time in the event of power failure	Program and settings in the controller : 10 years Program and settings in the plug-in memory : 10 year Data memory : 10 years	Program and settings in the plug-in memory : 10 years		
Cycle time	FBD : 6 →90 ms (typically 20 ms) Ladder : typically 20 ms			
Response time	Input acquisition time: 1 to 2 cycle times			
Clock data retention	10 years (lithium battery) at 25 °C			
Clock drift	Drift < 12 min/year (at 25 °C) 6 s/month (at 25 °C with user-definable correction of	drift)		
Timer block accuracy	1 % ± 2 cycle times	unity		
Start up time on power up	< 1,2 s			
Characteristics of products with AC power sup	plied			
Supply				
Nominal voltage	24 V AC	100 →24	0 V AC	
Operating limits	-15 % / +20 %	-15 % / +	10 %	
	or 20.4 V AC→28.8 V AC	or 85 V A	C→264 V AC	
Supply frequency range	50/60 Hz (+4 % / -6 %) or 47 →53 Hz/57 →63 Hz	50/60 Hz	(+ 4 % / - 6 %) or 47 →53 Hz/57 →63 Hz	
Immunity from micro power cuts	10 ms (repetition 20 times)	10 ms (re	petition 20 times)	
Max. absorbed power	CB12-CD12-XD10-XB10 : 4 VA		12-XD10-XB10 : 7 VA	
	CB20-CD20 : 6 VA		20 : 11 VA	
	XD10-XB10 with extension : 7.5 VA XD26-XB26 : 7.5 VA		10 with extension : 12 VA 26 : 12 VA	
	XD26-XB26 with extension : 10 VA		26 with extension : 17 VA	
Isolation voltage	1780 V AC	1780 V A	С	
Inputs				
Input voltage	24 V AC (-15 % / +20 %)		100 →240 V AC (-15 % / +10 %)	
Input current	4.4 mA @ 20.4 V AC 5.2 mA @ 24.0 V AC		0.24 mA @ 85 V AC	
	6.3 mA @ 28.8 V AC		0.75 mA @ 264 V AC	
Input impedance	4.6 kΩ		350 kΩ	
Logic 1 voltage threshold	≥ 14 V AC		≥ 79 V AC	
Making current at logic state 1 Logic 0 voltage threshold	> 2 mA ≤ 5 V AC		> 0.17 mA ≤ 20 V AC (≤ 28 V AC : XE10, XR06, XR10, XR14)	
Release current at logic state 0	< 0.5 mA		< 0.5 mA	
Response time with LADDER programming	50 ms		50 ms	
	State 0 →1 (50/60 Hz)		State 0 →1 (50/60 Hz)	
Response time with function blocks programming	Configurable in increments of 10 ms 50 ms min. up to 255 ms State 0 →1 (50/60 Hz)		Configurable in increments of 10 ms 50 ms min. up to 255 ms State 0 →1 (50/60 Hz)	
Maximum counting frequency	In accordance with cycle time (Tc) and input respons	e time (Tr):	In accordance with cycle time (Tc) and input response time (Tr):	
	1/ ((2 x Tc) + Tr)		1/ ((2 x Tc) + Tr)	
Sensor type	Contact or 3-wire PNP Resistive		Contact or 3-wire PNP Resistive	
Input type Isolation between power supply and inputs	None		None	
Isolation between inputs	None		None	
Protection against polarity inversions	Yes		Yes	
Status indicator	On LCD screen for CD and XD		On LCD screen for CD and XD	
Characteristics of relay outputs common to the	entire range			
Max. breaking voltage	5 →30 V DC			
Breaking current	24 →250 V AC			
Dieaking current	CB-CD-XD10-XB10-XR06-XR10 : 8 A XD26-XB26 : 8 x 8 A relays, 2 x 5 A relays XE10 : 4 x 5 A relays XR14 : 4 x 8 A relays, 2 x 5 A relays			
Electrical durability for 500 000 operating cycles	RBT (Removable Terminal Blocks) versions : verify the	ne maximum c	current according to the type of connection used	
Electrical durability for 500 000 operating cycles				
Max. Output Common Current	12 A for O8, O9, OA			
Minimum switching capacity	10 mA (at minimum voltage of 12 V)			
Minimum load	12 V, 10 mA			
Maximum rate	Off load: 10 Hz At operating current: 0.1 Hz			
Mechanical life	10,000,000 (operations)			
Voltage for withstanding shocks	In accordance with IEC/EN 60947-1 and IEC/EN 6066-	4-1 : 4 kV		
Off-cycle response time	Make 10 ms			
	Release 5 ms			

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Built-in protections	Against short-circuits: None			
	Against overvoltages and overloads : None	· ·		
Status indicator	On LCD screen for CD and XD			
Characteristics of product with DC power sup	plied			
Supply				
Nominal voltage	12 V DC	24 V DC		
Operating limits	-13 % / +20 %	-20 % / +25 %		
	or 10.4 V DC→14.4 V DC (including ripple)) or 19.2 V DC→30 V DC (including ripple)		
Immunity from micro power cuts	≤ 1 ms (repetition 20 times)	≤1 ms (repetition 20 times)		
Max. absorbed power	CB12 with solid state outputs : 1.5 W CD12 : 1.5 W CD20 : 2.5 W XD26-XB26 : 3 W	CB12-CD12-CD20 with solid state outputs - XD10-XB10 with solid state outputs : XD10-XB10 with relay outputs : 4 W XD26-XB26 with solid state outputs : 5 W CB20-CD20 with relay outputs : 6 W XD26 with relay outputs : 6 W XD10-XB10 with extension : 8 W XD26-XB26 with extension : 10 W		
	XD26-XB26 : 3 W XD26-XB26 with extension : 5 W XD26 with solid state outputs : 2.5 W			
Protection against polarity inversions	Yes	Yes		
Digital inputs (I1 to IA and IH to IY)				
Input voltage	12 V DC (-13 % / +20 %)		24 V DC (-20 % / +25 %)	
Input current	3.9 mA @ 10.44 V DC		2.6 mA @ 19.2 V DC	
	4.4 mA @ 12.0 V DC		3.2 mA @ 24 V DC	
	5.3 mA @ 14.4 VDC		4.0 mA @ 30.0 VDC	
Input impedance	2.7 kΩ		7.4 kΩ	
Logic 1 voltage threshold	≥7 V DC		≥ 15 V DC	
Making current at logic state 1	≥ 2 mA		≥ 2.2 mA	
Logic 0 voltage threshold	≤ 3 V DC		≤5 V DC	
Release current at logic state 0	< 0.9 mA		< 0.75 mA	
Response time	1 →2 cycle times + 6 ms	(4 - -	$1 \rightarrow 2$ cycle times + 6 ms	
Maximum counting frequency	Inputs 11 & I2 : FBD (up to 6 k Hz) & Ladder Inputs I3 to IA & IH to IY : In accordance with input response time (Tr) : 1/ ((2 x Tc) + Tr)	h cycle time (Tc) and	Inputs I1 & I2 : FBD (up to 6 k Hz) & Ladder (1 k Hz) Inputs I3 to IA & IH to IY : In accordance with cycle time (Tc) and input response time (Tr) : 1/ ((2 x Tc) + Tr)	
Sensor type	Contact or 3-wire PNP		Contact or 3-wire PNP	
Conforming to IEC/EN 61131-2	Type 1		Type 1	
Input type	Resistive		Resistive	
Isolation between power supply and inputs	None		None None	
Isolation between inputs	None Yes		Yes	
Protection against polarity inversions Status indicator	On LCD screen for CD and XD		On LCD screen for CD and XD	
	On LOD Screen for CD and AD		Off EGD Scieen for GD and AD	
Analogue or digital inputs (IB to IG)				
CB12-CD12-XD10-XB10	4 inputs IB →IE		4 inputs IB →IE	
CB20-CD20-XB26-XD26	6 inputs IB →IG		6 inputs IB →IG	
Inputs used as analogue inputsonly in FBD				
Measurement range	$(0 \rightarrow 10 \text{ V}) \text{ or } (0 \rightarrow \text{V power supply})$		$(0 \rightarrow 10 \text{ V}) \text{ or } (0 \rightarrow \text{V power supply})$	
Input impedance			12 kΩ	
Input voltage			30 V DC max.	
Value of LSB			29 mV	
Input type	Common mode		Common mode	
Resolution			10 bit at max. input voltage	
Conversion time			Controller cycle time	
Accuracy at 25 °C			± 5 %	
Accuracy at 55 °C	± 6.2 %		± 6.2 %	
Repeat accuracy at 55 °C	± 2 %		± 2 %	
Isolation between analogue channel and power supp		(' ()	None	
Cable length Protection against polarity inversions	10 m maximum, with shielded cable (sensor	not isolated)	10 m maximum, with shielded cable (sensor not isolated)	
Protection against polarity inversions Potentiometer control	Yes 2.2 kΩ/0.5 W (recommended)		Yes 2.2 kΩ/0.5 W (recommended)	
1 oteritionneter control	2.2 KΩ/0.5 W (recommended) 10 kΩ max.		2.2 Ω /0.5 W (recommended) 10 kΩ max.	
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The state of the property of				
Inputs used as digital inputs	40 V DO / 45 27 / 20 27		011/100/000//-050/	
Input voltage	12 V DC (-13 % / +20 %)		24 V DC (-20 % / +25 %)	
	0.7 mA @ 10.44 VDC		1.6 mA @ 19.2 VDC	
Input voltage	0.7 mA @ 10.44 VDC 0.9 mA @ 12.0 VDC		1.6 mA @ 19.2 VDC 2.0 mA @ 24.0 V DC	
Input voltage Input current	0.7 mA @ 10.44 VDC 0.9 mA @ 12.0 VDC 1.0 mA @ 14.4VDC		1.6 mA @ 19.2 VDC	
Input voltage Input current Input impedance	0.7 mA @ 10.44 VDC 0.9 mA @ 12.0 VDC 1.0 mA @ 14.4VDC 14 kΩ		1.6 mA @ 19.2 VDC 2.0 mA @ 24.0 V DC 2.5 mA @ 30.0 VDC 12 kΩ	
Input voltage Input current Input impedance Logic 1 voltage threshold	0.7 mA @ 10.44 VDC 0.9 mA @ 12.0 VDC 1.0 mA @ 14.4VDC 14 kΩ ≥ 7 V DC		1.6 mA @ 19.2 VDC 2.0 mA @ 24.0 V DC 2.5 mA @ 30.0 VDC 12 kΩ ≥ 15 VDC	
Input voltage Input current Input impedance Logic 1 voltage threshold Making current at logic state 1	0.7 mA @ 10.44 VDC 0.9 mA @ 12.0 VDC 1.0 mA @ 14.4VDC 14 kΩ		1.6 mA @ 19.2 VDC 2.0 mA @ 24.0 V DC 2.5 mA @ 30.0 VDC 12 kΩ	
Input voltage Input current Input impedance Logic 1 voltage threshold Making current at logic state 1 Logic 0 voltage threshold	0.7 mA @ 10.44 VDC 0.9 mA @ 12.0 VDC 1.0 mA @ 14.4VDC 14 kΩ ≥ 7 V DC ≥ 0.5 mA		1.6 mA @ 19.2 VDC 2.0 mA @ 24.0 V DC 2.5 mA @ 30.0 VDC 12 kΩ ≥ 15 VDC ≥ 1.2 mA	
Input voltage Input current Input impedance Logic 1 voltage threshold Making current at logic state 1	0.7 mA @ 10.44 VDC 0.9 mA @ 12.0 VDC 1.0 mA @ 14.4VDC 14 kΩ ≥ 7 V DC ≥ 0.5 mA ≤ 3 V DC		1.6 mA @ 19.2 VDC 2.0 mA @ 24.0 V DC 2.5 mA @ 30.0 VDC 12 kΩ ≥ 15 VDC ≥ 1.2 mA ≤ 5 V DC	
Input voltage Input current Input impedance Logic 1 voltage threshold Making current at logic state 1 Logic 0 voltage threshold Release current at logic state 0	0.7 mA @ 10.44 VDC 0.9 mA @ 12.0 VDC 1.0 mA @ 14.4VDC 14 kΩ ≥ 7 V DC ≥ 0.5 mA ≤ 3 V DC ≤ 0.2 mA	t response time (Tr):	1.6 mA @ 19.2 VDC 2.0 mA @ 24.0 V DC 2.5 mA @ 30.0 VDC 12 kΩ ≥ 15 VDC ≥ 1.2 mA ≤ 5 V DC ≤ 0.5 mA	
Input voltage Input current Input impedance Logic 1 voltage threshold Making current at logic state 1 Logic 0 voltage threshold Release current at logic state 0 Response time	0.7 mA @ 10.44 VDC 0.9 mA @ 12.0 VDC 1.0 mA @ 14.4VDC 14 kΩ ≥ 7 V DC ≥ 0.5 mA ≤ 3 V DC ≤ 0.2 mA 1 →2 cycle times	t response time (Tr):	1.6 mA @ 19.2 VDC 2.0 mA @ 24.0 V DC 2.5 mA @ 30.0 VDC 12 kΩ ≥ 15 VDC ≥ 1.2 mA ≤ 5 V DC ≤ 0.5 mA 1 →2 cycle times	
Input voltage Input current Input impedance Logic 1 voltage threshold Making current at logic state 1 Logic 0 voltage threshold Release current at logic state 0 Response time	0.7 mA @ 10.44 VDC 0.9 mA @ 12.0 VDC 1.0 mA @ 14.4VDC 14 kΩ ≥ 7 V DC ≥ 0.5 mA ≤ 3 V DC ≤ 0.2 mA 1 →2 cycle times In accordance with cycle time (Tc) and inpu	t response time (Tr):	1.6 mA @ 19.2 VDC 2.0 mA @ 24.0 V DC 2.5 mA @ 30.0 VDC 12 kΩ ≥ 15 VDC ≥ 1.2 mA ≤ 5 V DC ≤ 0.5 mA 1 →2 cycle times In accordance with cycle time (Tc) and input response time (Tr) :	
Input voltage Input current Input impedance Logic 1 voltage threshold Making current at logic state 1 Logic 0 voltage threshold Release current at logic state 0 Response time Maximum counting frequency in FBD	0.7 mA @ 10.44 VDC 0.9 mA @ 12.0 VDC 1.0 mA @ 14.4VDC 14 kΩ ≥ 7 V DC ≥ 0.5 mA ≤ 3 V DC ≤ 0.2 mA 1 →2 cycle times In accordance with cycle time (Tc) and inpu 1/ ((2 x Tc) + Tr)	t response time (Tr):	1.6 mA @ 19.2 VDC 2.0 mA @ 24.0 V DC 2.5 mA @ 30.0 VDC 12 kΩ ≥ 15 VDC ≥ 1.2 mA ≤ 5 V DC ≤ 0.5 mA 1 →2 cycle times In accordance with cycle time (Tc) and input response time (Tr): 1/ ((2 x Tc) + Tr)	
Input voltage Input current Input impedance Logic 1 voltage threshold Making current at logic state 1 Logic 0 voltage threshold Release current at logic state 0 Response time Maximum counting frequency in FBD Sensor type	0.7 mA @ 10.44 VDC 0.9 mA @ 12.0 VDC 1.0 mA @ 14.4VDC 14 kΩ ≥ 7 V DC ≥ 0.5 mA ≤ 3 V DC ≤ 0.2 mA 1 →2 cycle times In accordance with cycle time (Tc) and inpu 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP	t response time (Tr):	1.6 mA @ 19.2 VDC 2.0 mA @ 24.0 V DC 2.5 mA @ 30.0 VDC 12 kΩ ≥ 15 VDC ≥ 1.2 mA ≤ 5 V DC ≤ 0.5 mA 1 →2 cycle times In accordance with cycle time (Tc) and input response time (Tr): 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP	
Input voltage Input current Input impedance Logic 1 voltage threshold Making current at logic state 1 Logic 0 voltage threshold Release current at logic state 0 Response time Maximum counting frequency in FBD Sensor type Conforming to IEC/EN 61131-2	0.7 mA @ 10.44 VDC 0.9 mA @ 12.0 VDC 1.0 mA @ 14.4 VDC 14 kΩ ≥ 7 V DC ≥ 0.5 mA ≤ 3 V DC ≤ 0.2 mA 1 →2 cycle times In accordance with cycle time (Tc) and inpu 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP Type 1	t response time (Tr):	1.6 mA @ 19.2 VDC 2.0 mA @ 24.0 V DC 2.5 mA @ 30.0 VDC 12 kΩ ≥ 15 VDC ≥ 1.2 mA ≤ 5 V DC ≤ 0.5 mA 1 →2 cycle times In accordance with cycle time (Tc) and input response time (Tr): 1/((2 x Tc) + Tr) Contact or 3-wire PNP Type 1	
Input voltage Input current Input impedance Logic 1 voltage threshold Making current at logic state 1 Logic 0 voltage threshold Release current at logic state 0 Response time Maximum counting frequency in FBD Sensor type Conforming to IEC/EN 61131-2 Input type	0.7 mA @ 10.44 VDC 0.9 mA @ 12.0 VDC 1.0 mA @ 14.4 VDC 14 kΩ ≥ 7 V DC ≥ 0.5 mA ≤ 3 V DC ≤ 0.2 mA 1 →2 cycle times In accordance with cycle time (Tc) and inputh ((2 x Tc) + Tr) Contact or 3-wire PNP Type 1 Resistive	t response time (Tr):	1.6 mA @ 19.2 VDC 2.0 mA @ 24.0 V DC 2.5 mA @ 30.0 VDC 12 kΩ ≥ 15 VDC ≥ 1.2 mA ≤ 5 V DC ≤ 0.5 mA 1 →2 cycle times In accordance with cycle time (Tc) and input response time (Tr): 1/((2 x Tc) + Tr) Contact or 3-wire PNP Type 1 Resistive	
Input voltage Input current Input impedance Logic 1 voltage threshold Making current at logic state 1 Logic 0 voltage threshold Release current at logic state 0 Response time Maximum counting frequency in FBD Sensor type Conforming to IEC/EN 61131-2 Input type Isolation between power supply and inputs Isolation against polarity inversions	0.7 mA @ 10.44 VDC 0.9 mA @ 12.0 VDC 1.0 mA @ 14.4VDC 14 kΩ ≥ 7 V DC ≥ 0.5 mA ≤ 3 V DC ≤ 0.2 mA 1 →2 cycle times In accordance with cycle time (Tc) and inputh (1/2 x Tc) + Tr) Contact or 3-wire PNP Type 1 Resistive None None Yes	t response time (Tr):	1.6 mA @ 19.2 VDC 2.0 mA @ 24.0 V DC 2.5 mA @ 30.0 VDC 12 kΩ ≥ 15 VDC ≥ 1.2 mA ≤ 5 V DC ≤ 0.5 mA 1 → 2 cycle times In accordance with cycle time (Tc) and input response time (Tr): 1/((2 x Tc) + Tr) Contact or 3-wire PNP Type 1 Resistive None None Yes	
Input voltage Input current Input impedance Logic 1 voltage threshold Making current at logic state 1 Logic 0 voltage threshold Release current at logic state 0 Response time Maximum counting frequency in FBD Sensor type Conforming to IEC/EN 61131-2 Input type Isolation between power supply and inputs Isolation between inputs	0.7 mA @ 10.44 VDC 0.9 mA @ 12.0 VDC 1.0 mA @ 14.4 VDC 14 kΩ ≥ 7 V DC ≥ 0.5 mA ≤ 3 V DC ≤ 0.2 mA 1 →2 cycle times In accordance with cycle time (Tc) and inpu 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP Type 1 Resistive None None	t response time (Tr):	1.6 mA @ 19.2 VDC 2.0 mA @ 24.0 V DC 2.5 mA @ 30.0 VDC 12 kΩ ≥ 15 VDC ≥ 1.2 mA ≤ 5 V DC ≤ 0.5 mA 1 →2 cycle times In accordance with cycle time (Tc) and input response time (Tr): 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP Type 1 Resistive None None	

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Max. breaking voltage	5 →30 V DC 24 →250 V AC	
N . O O O		
Max. Output Common Current	12A (10A UL) for O8, O9, OA	
Breaking current	CB-CD-XD10-XB10-XR06-XR10 : 8 A	
	XD26-XB26: 8 x 8 A relays, 2 x 5 A relays XE10: 4 x 5 A relays	
	XR14: 4 x 8 A relays, 2 x 5 A relays	
Electrical durability for 500 000 operating cycles	Utilization category DC-12 : 24 V, 1.5 A	
Electrical datability for ede operating by clos	Utilization category DC-13 : 24 V (L/R = 10 ms), 0.6 A	
	Utilization category AC-12 : 230 V, 1.5 A	
	Utilization category AC-15 : 230 V, 0.9 A	
Minimum switching capacity	10 mA (at minimum voltage of 12 V)	
Minimum load	12 V, 10 mA	
Maximum rate	Off load : 10 Hz	
	At operating current : 0.1 Hz	
Mechanical life	10,000,000 (operations)	
Voltage for withstanding shocks	In accordance with IEC/EN 60947-1 and IEC/EN 60664-1: 4 kV	
Off-cycle response time	Make 10 ms	
	Release 5 ms	
Built-in protections	Against short-circuits : None	
	Against overvoltages and overloads : None	
Status indicator	On LCD screen for CD and XD	
Digital / PWM solid state output		
PWM solid state output*	CB12: O4	CD12-XD10-XB10 : O4
	XD26 : O4 →O7	CD20-XD26-XB26 : O4 →O7
* Only available with "FBD" programming language	* Only available with "FBD" programming language	
Breaking voltage	10.4 →30 V DC	19.2 →30 V DC
Nominal voltage	12-24 VDC	24 V DC

Digital / PWM solid state output		
PWM solid state output*	CB12: O4	CD12-XD10-XB10: O4
	XD26 : O4 →O7	CD20-XD26-XB26 : O4 →O7
* Only available with "FBD" programming language	* Only available with "FBD" programming language	
Breaking voltage	10.4 →30 V DC	19.2 →30 V DC
Nominal voltage	12-24 VDC	24 V DC
Nominal current	0.5 A	0.5 A
Max. breaking current	0,625 A	0,625 A
Voltage drop	≤ 2 V for I = 0.5 A (at state 1)	≤ 2 V for I = 0.5 A (at state 1)
Response time	Make ≤ 1 ms	Make ≤ 1 ms
	Release ≤ 1 ms	Release ≤ 1 ms
Operating frequency	1 Maximum on inductive load	1 Maximum on inductive load
Built-in protections	Against overloads and short-circuits : Yes	Against overloads and short-circuits : Yes
	Against overvoltages (*) : Yes	Against overvoltages (*) : Yes
	Against inversions of power supply : Yes	Against inversions of power supply : Yes
	(*) In the absence of a volt-free contact between the logic	(*) In the absence of a volt-free contact between the logic
	controller output and the load	controller output and the load
Min. load	1 mA	1 mA
Maximum incandescent load	0,2 A / 12 V DC	0,1 A / 24 V DC
	0,1 A / 24 V DC	· ·
Galvanic isolation	No	No
PWM frequency	14.11 Hz	14.11 Hz
	56.45 Hz	56.45 Hz
	112.90 Hz	112.90 Hz
	225.80 Hz	225.80 Hz
	451.59 Hz 1806.37 Hz	451.59 Hz 1806.37 Hz
DIAMA surelia seria		
PWM cyclic ratio	0 →100 % (256 steps for CD, XD and 1024 steps for XA)	0 →100 % (256 steps for CD, XD and 1024 steps for XA)
Max. Breaking current PWM	50 mA	50 mA
Max. cable length PWM	20 m	20 m
PWM accuracy at 120 Hz	< 5 % (20 % →80 %) load at 10 mA	< 5 % (20 % →80 %) load at 10 mA
PWM accuracy at 500 Hz Status indicator	< 10 % (20 % →80 %) load at 10 mA	< 10 % (20 % →80 %) load at 10 mA
	On LCD screen for XD	On LCD screen for CD and XD

Accessories

Туре	Description	Code
M3 Soft	Multilingual programming software containing specific library functions (CD-ROM)	88970111
PA	EEPROM memory cartridge	88970108
PA	3 m serial link cable : PC →Millenium 3	88970102
PA	USB cable 3 m : PC →Millenium 3	88970109
PA	Millenium 3 interface →Bluetooth® (class A 10 m)	88970104

Comments

* to be marketed 1st quarter 2006

Dimensions (mm) CB20 Smart

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